# SII •

# S-5844A Series

# **TEMPERATURE SWITCH IC (THERMOSTAT IC)**

www.sii-ic.com

© SII Semiconductor Corporation, 2011-2014

Rev.2.6\_01

The S-5844A Series is a temperature switch IC (thermostat IC) which detects the temperature with a temperature accuracy of  $\pm 2.5^{\circ}$ C. The output inverts when temperature reaches the detection temperature. The S-5844A Series restores the output voltage when the temperature drops to the level of release temperature.

The S-5844A Series operates at the lower power supply voltage of 1.65 V and its current consumption is 0.18  $\mu$ A typ. due to CMOS configuration.

A temperature sensor with the negative temperature coefficient, a reference voltage generation circuit and a comparator are integrated on one chip, and enclosed into the packages SOT-23-5 and SNT-4A, and the super-small package HSNT-4 (1010).

#### **■** Features

Detection temperature: T<sub>DET</sub> = +50°C to +100°C, +5°C step, detection accuracy: ±2.5°C

• Low voltage operation: V<sub>DD</sub> = 1.65 V min.

Low current consumption: I<sub>DD</sub> = 0.18 μA typ. (Ta = +25°C)
 Hysteresis temperature: selectable in 5°C, 10°C, 15°C or 20°C

Selectable output logic in active "H" or active "L"

Selectable output form in CMOS or Nch open-drain

• Operation temperature range: Ta = -40°C to +125°C

• Lead-free (Sn 100%), halogen-free

## ■ Applications

- Fan control
- · Air conditioning system
- Mobile phone
- Game console
- · Various electronic devices

#### ■ Packages

- SOT-23-5
- SNT-4A
- HSNT-4 (1010)

# **■** Block Diagrams

### 1. CMOS output product

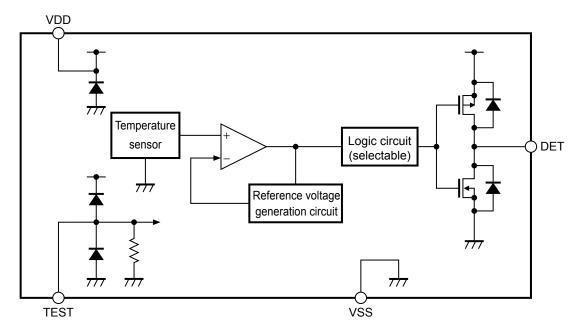


Figure 1

### 2. Nch open-drain output product

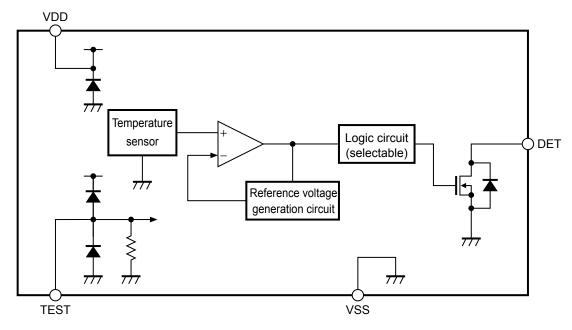
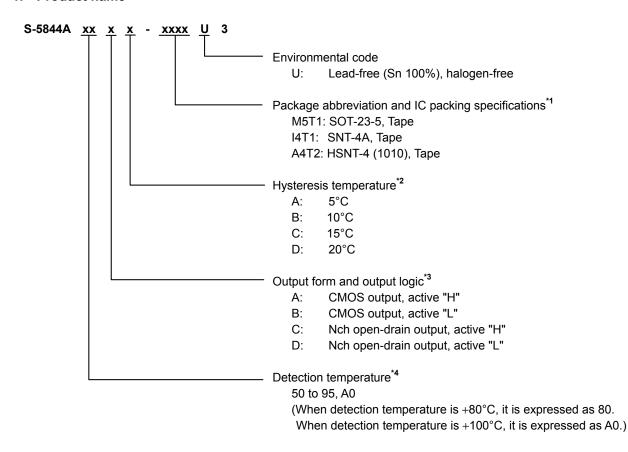


Figure 2

#### **■ Product Name Structure**

Users are able to select the detection temperature, output form and logic, hysteresis temperature, and package for the S-5844A Series.

#### 1. Product name



- \*1. Refer to the tape drawing.
- **\*2.** The hysteresis temperature is selectable in 5°C, 10°C, 15°C, or 20°C. However, if the detection temperature is +50°C, select the hysteresis temperature in 5°C or 10°C.
- **\*3.** For the DET pin output, selectable the output logic active "H" or active "L". For the DET pin output, selectable the output form CMOS or Nch open-drain.
- \*4. Detection temperature (TDET) is settable in +50°C to +100°C, in +5°C step.

#### 2. Packages

**Table 1 Package Drawing Codes** 

Package Name	Dimension	Tape Reel L		Land
SOT-23-5	MP005-A-P-SD	MP005-A-C-SD	MP005-A-R-SD	_
SNT-4A	PF004-A-P-SD	PF004-A-C-SD	PF004-A-R-SD	PF004-A-L-SD
HSNT-4 (1010)	PL004-A-P-SD	PL004-A-C-SD	PL004-A-R-SD	PL004-A-L-SD

## 3. Product name list

#### 3.1 SOT-23-5

Table 2

Product Name	Detection Temperature (TDET)	DET Pin Output Form	DET Pin Output Logic	Hysteresis Temperature (T <sub>HYS</sub> )
S-5844A50DB-M5T1U3	+50°C	Nch open-drain	Active "L"	10°C
S-5844A55CB-M5T1U3	+55°C	Nch open-drain	Active "H"	10°C
S-5844A55CC-M5T1U3	+55°C	Nch open-drain	Active "H"	15°C
S-5844A55CD-M5T1U3	+55°C	Nch open-drain	Active "H"	20°C
S-5844A55DB-M5T1U3	+55°C	Nch open-drain	Active "L"	10°C
S-5844A60CB-M5T1U3	+60°C	Nch open-drain	Active "H"	10°C
S-5844A60CC-M5T1U3	+60°C	Nch open-drain	Active "H"	15°C
S-5844A60CD-M5T1U3	+60°C	Nch open-drain	Active "H"	20°C
S-5844A60DB-M5T1U3	+60°C	Nch open-drain	Active "L"	10°C
S-5844A65CB-M5T1U3	+65°C	Nch open-drain	Active "H"	10°C
S-5844A65CC-M5T1U3	+65°C	Nch open-drain	Active "H"	15°C
S-5844A65CD-M5T1U3	+65°C	Nch open-drain	Active "H"	20°C
S-5844A65DA-M5T1U3	+65°C	Nch open-drain	Active "L"	5°C
S-5844A65DB-M5T1U3	+65°C	Nch open-drain	Active "L"	10°C
S-5844A70CB-M5T1U3	+70°C	Nch open-drain	Active "H"	10°C
S-5844A70CC-M5T1U3	+70°C	Nch open-drain	Active "H"	15°C
S-5844A70CD-M5T1U3	+70°C	Nch open-drain	Active "H"	20°C
S-5844A70DB-M5T1U3	+70°C	Nch open-drain	Active "L"	10°C
S-5844A75CB-M5T1U3	+75°C	Nch open-drain	Active "H"	10°C
S-5844A75CC-M5T1U3	+75°C	Nch open-drain	Active "H"	15°C
S-5844A75CD-M5T1U3	+75°C	Nch open-drain	Active "H"	20°C
S-5844A75DB-M5T1U3	+75°C	Nch open-drain	Active "L"	10°C
S-5844A80CB-M5T1U3	+80°C	Nch open-drain	Active "H"	10°C
S-5844A80CC-M5T1U3	+80°C	Nch open-drain	Active "H"	15°C
S-5844A80CD-M5T1U3	+80°C	Nch open-drain	Active "H"	20°C
S-5844A80DB-M5T1U3	+80°C	Nch open-drain	Active "L"	10°C
S-5844A85CB-M5T1U3	+85°C	Nch open-drain	Active "H"	10°C
S-5844A85CC-M5T1U3	+85°C	Nch open-drain	Active "H"	15°C
S-5844A85CD-M5T1U3	+85°C	Nch open-drain	Active "H"	20°C
S-5844A85DB-M5T1U3	+85°C	Nch open-drain	Active "L"	10°C
S-5844A90CB-M5T1U3	+90°C	Nch open-drain	Active "H"	10°C
S-5844A90CC-M5T1U3	+90°C	Nch open-drain	Active "H"	15°C
S-5844A90CD-M5T1U3	+90°C	Nch open-drain	Active "H"	20°C
S-5844A90DB-M5T1U3	+90°C	Nch open-drain	Active "L"	10°C
S-5844A95CB-M5T1U3	+95°C	Nch open-drain	Active "H"	10°C
S-5844A95CC-M5T1U3	+95°C	Nch open-drain	Active "H"	15°C
S-5844A95CD-M5T1U3	+95°C	Nch open-drain	Active "H"	20°C
S-5844A95DB-M5T1U3	+95°C	Nch open-drain	Active "L"	10°C

**Remark** Please contact our sales office for products with specifications other than the above.

### 3. 2 SNT-4A

Table 3

Product Name	Detection Temperature (T <sub>DET</sub> )	DET Pin Output Form	DET Pin Output Logic	Hysteresis Temperature (T <sub>HYS</sub> )
S-5844A50DB-I4T1U3	+50°C	Nch open-drain	Active "L"	10°C
S-5844A55CB-I4T1U3	+55°C	Nch open-drain	Active "H"	10°C
S-5844A55CC-I4T1U3	+55°C	Nch open-drain	Active "H"	15°C
S-5844A55CD-I4T1U3	+55°C	Nch open-drain	Active "H"	20°C
S-5844A55DB-I4T1U3	+55°C	Nch open-drain	Active "L"	10°C
S-5844A60CB-I4T1U3	+60°C	Nch open-drain	Active "H"	10°C
S-5844A60CC-I4T1U3	+60°C	Nch open-drain	Active "H"	15°C
S-5844A60CD-I4T1U3	+60°C	Nch open-drain	Active "H"	20°C
S-5844A60DB-I4T1U3	+60°C	Nch open-drain	Active "L"	10°C
S-5844A65CB-I4T1U3	+65°C	Nch open-drain	Active "H"	10°C
S-5844A65CC-I4T1U3	+65°C	Nch open-drain	Active "H"	15°C
S-5844A65CD-I4T1U3	+65°C	Nch open-drain	Active "H"	20°C
S-5844A65DB-I4T1U3	+65°C	Nch open-drain	Active "L"	10°C
S-5844A70CB-I4T1U3	+70°C	Nch open-drain	Active "H"	10°C
S-5844A70CC-I4T1U3	+70°C	Nch open-drain	Active "H"	15°C
S-5844A70CD-I4T1U3	+70°C	Nch open-drain	Active "H"	20°C
S-5844A70DB-I4T1U3	+70°C	Nch open-drain	Active "L"	10°C
S-5844A75CB-I4T1U3	+75°C	Nch open-drain	Active "H"	10°C
S-5844A75CC-I4T1U3	+75°C	Nch open-drain	Active "H"	15°C
S-5844A75CD-I4T1U3	+75°C	Nch open-drain	Active "H"	20°C
S-5844A75DB-I4T1U3	+75°C	Nch open-drain	Active "L"	10°C
S-5844A80CB-I4T1U3	+80°C	Nch open-drain	Active "H"	10°C
S-5844A80CC-I4T1U3	+80°C	Nch open-drain	Active "H"	15°C
S-5844A80CD-I4T1U3	+80°C	Nch open-drain	Active "H"	20°C
S-5844A80DB-I4T1U3	+80°C	Nch open-drain	Active "L"	10°C
S-5844A85CB-I4T1U3	+85°C	Nch open-drain	Active "H"	10°C
S-5844A85CC-I4T1U3	+85°C	Nch open-drain	Active "H"	15°C
S-5844A85CD-I4T1U3	+85°C	Nch open-drain	Active "H"	20°C
S-5844A85DB-I4T1U3	+85°C	Nch open-drain	Active "L"	10°C
S-5844A90CB-I4T1U3	+90°C	Nch open-drain	Active "H"	10°C
S-5844A90CC-I4T1U3	+90°C	Nch open-drain	Active "H"	15°C
S-5844A90CD-I4T1U3	+90°C	Nch open-drain	Active "H"	20°C
S-5844A90DB-I4T1U3	+90°C	Nch open-drain	Active "L"	10°C
S-5844A95CB-I4T1U3	+95°C	Nch open-drain	Active "H"	10°C
S-5844A95CC-I4T1U3	+95°C	Nch open-drain	Active "H"	15°C
S-5844A95CD-I4T1U3	+95°C	Nch open-drain	Active "H"	20°C
S-5844A95DB-I4T1U3	+95°C	Nch open-drain	Active "L"	10°C

**Remark** Please contact our sales office for products with specifications other than the above.

### 3. 3 HSNT-4 (1010)

Table 4

Product Name	Detection Temperature (TDET)	DET Pin Output Form	DET Pin Output Logic	Hysteresis Temperature (T <sub>HYS</sub> )
S-5844A50DB-A4T2U3	+50°C	Nch open-drain	Active "L"	10°C
S-5844A55CB-A4T2U3	+55°C	Nch open-drain	Active "H"	10°C
S-5844A55CC-A4T2U3	+55°C	Nch open-drain	Active "H"	15°C
S-5844A55CD-A4T2U3	+55°C	Nch open-drain	Active "H"	20°C
S-5844A55DB-A4T2U3	+55°C	Nch open-drain	Active "L"	10°C
S-5844A60CB-A4T2U3	+60°C	Nch open-drain	Active "H"	10°C
S-5844A60CC-A4T2U3	+60°C	Nch open-drain	Active "H"	15°C
S-5844A60CD-A4T2U3	+60°C	Nch open-drain	Active "H"	20°C
S-5844A60DB-A4T2U3	+60°C	Nch open-drain	Active "L"	10°C
S-5844A65CB-A4T2U3	+65°C	Nch open-drain	Active "H"	10°C
S-5844A65CC-A4T2U3	+65°C	Nch open-drain	Active "H"	15°C
S-5844A65CD-A4T2U3	+65°C	Nch open-drain	Active "H"	20°C
S-5844A65DB-A4T2U3	+65°C	Nch open-drain	Active "L"	10°C
S-5844A70CB-A4T2U3	+70°C	Nch open-drain	Active "H"	10°C
S-5844A70CC-A4T2U3	+70°C	Nch open-drain	Active "H"	15°C
S-5844A70CD-A4T2U3	+70°C	Nch open-drain	Active "H"	20°C
S-5844A70DB-A4T2U3	+70°C	Nch open-drain	Active "L"	10°C
S-5844A75CB-A4T2U3	+75°C	Nch open-drain	Active "H"	10°C
S-5844A75CC-A4T2U3	+75°C	Nch open-drain	Active "H"	15°C
S-5844A75CD-A4T2U3	+75°C	Nch open-drain	Active "H"	20°C
S-5844A75DB-A4T2U3	+75°C	Nch open-drain	Active "L"	10°C
S-5844A80CB-A4T2U3	+80°C	Nch open-drain	Active "H"	10°C
S-5844A80CC-A4T2U3	+80°C	Nch open-drain	Active "H"	15°C
S-5844A80CD-A4T2U3	+80°C	Nch open-drain	Active "H"	20°C
S-5844A80DB-A4T2U3	+80°C	Nch open-drain	Active "L"	10°C
S-5844A85CB-A4T2U3	+85°C	Nch open-drain	Active "H"	10°C
S-5844A85CC-A4T2U3	+85°C	Nch open-drain	Active "H"	15°C
S-5844A85CD-A4T2U3	+85°C	Nch open-drain	Active "H"	20°C
S-5844A85DB-A4T2U3	+85°C	Nch open-drain	Active "L"	10°C
S-5844A90CB-A4T2U3	+90°C	Nch open-drain	Active "H"	10°C
S-5844A90CC-A4T2U3	+90°C	Nch open-drain	Active "H"	15°C
S-5844A90CD-A4T2U3	+90°C	Nch open-drain	Active "H"	20°C
S-5844A90DB-A4T2U3	+90°C	Nch open-drain	Active "L"	10°C
S-5844A95CB-A4T2U3	+95°C	Nch open-drain	Active "H"	10°C
S-5844A95CC-A4T2U3	+95°C	Nch open-drain	Active "H"	15°C
S-5844A95CD-A4T2U3	+95°C	Nch open-drain	Active "H"	20°C
S-5844A95DB-A4T2U3	+95°C	Nch open-drain	Active "L"	10°C

**Remark** Please contact our sales office for products with specifications other than the above.

## ■ Pin Configurations

#### 1. SOT-23-5

Top view



Figure 3

Table 5

Pin No.	Symbol	Description
1	TEST*1	Test pin
2	VSS	GND pin
3	DET	Output pin
4	NC*2	No connection
5	VDD	Power supply pin

- \*1. Connect the TEST pin to the VSS pin, or leave it open.
- **\*2.** The NC pin is electrically open.

  The NC pin can be connected to the VDD pin or the VSS pin.

#### 2. SNT-4A

Top view



Figure 4

#### Table 6

Pin No.	Symbol	Description
1	DET	Output pin
2	VSS	GND pin
3	TEST*1	Test pin
4	VDD	Power supply pin

<sup>\*1.</sup> Connect the TEST pin to the VSS pin, or leave it open.

#### 3. HSNT-4 (1010)

Top view

Bottom view



Table 7

Pin No.	Symbol	Description
1	DET	Output pin
2	VSS	GND pin
3	TEST*1	Test pin
4	VDD	Power supply pin

<sup>\*1.</sup> Connect the TEST pin to the VSS pin, or leave it open.

\*1. Connect the heat sink of backside at shadowed area to the board, and set electric potential open or GND. However, do not use it as the function of electrode.

Figure 5

## ■ Absolute Maximum Ratings

Table 8

(Ta =  $+25^{\circ}$ C unless otherwise specified)

Item		Symbol	Absolute Maximum Rating	Unit
Power supply voltage (Vss = 0 V)		$V_{DD}$	V <sub>SS</sub> + 6.0	V
Pin voltage		V <sub>TEST</sub>	$V_{SS} - 0.3$ to $V_{DD} + 0.3$	٧
CMOS output product		\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	$V_{SS} - 0.3$ to $V_{DD} + 0.3$	<b>&gt;</b>
Output voltage	Nch open-drain output product	V <sub>DET</sub>	$V_{SS} - 0.3$ to $V_{SS} + 6.0$	<b>V</b>
0.44	Pch driving current	I <sub>DETH</sub>	10	mA
Output pin current	Nch driving current	I <sub>DETL</sub>	10	mA
	SOT-23-5		600*1	mW
Power dissipation	SNT-4A	P <sub>D</sub>	300*1	mW
	HSNT-4 (1010)		340* <sup>1</sup>	mW
Operation ambient temperature		Topr	-40 to +125	°C
Storage temperatur	e	T <sub>stg</sub>	-55 to +150	°C

<sup>\*1.</sup> When mounted on board

[Mounted board]

(1) Board size: 114.3 mm  $\times$  76.2 mm  $\times$  t1.6 mm (2) Board name: JEDEC STANDARD51-7

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

#### **■ DC Electrical Characteristics**

#### 1. CMOS output product

Table 9

 $(V_{DD} = 3.0 \text{ V}, \text{ Ta} = +25^{\circ}\text{C} \text{ unless otherwise specified})$ 

			(	,			/
Item	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Power supply voltage	$V_{DD}$	_	1.65	_	5.5	V	1
Detection temperature*1	+T <sub>D</sub>	_	T <sub>DET</sub> – 2.5	T <sub>DET</sub>	T <sub>DET</sub> + 2.5	å	1
Hysteresis temperature*2	T <sub>HYS</sub>	_	_	5, 10, 15, 20	_	å	1
Output valtage	V <sub>DETH</sub>	I <sub>DETH</sub> = 0.5 mA	$V_{DD}-0.5$	_	_	٧	2
Output voltage	V <sub>DETL</sub>	$I_{DETL} = 0.5 \text{ mA}$	_	_	0.5	٧	3
Current consumption during operation	I <sub>DD</sub>	_	_	0.18	0.5	μΑ	1

<sup>\*1.</sup> T<sub>DET</sub>: Set value of detection temperature

#### 2. Nch open-drain output product

Table 10

 $(V_{DD} = 3.0 \text{ V}, \text{ Ta} = +25^{\circ}\text{C} \text{ unless otherwise specified})$ 

Item	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Power supply voltage	$V_{DD}$	_	1.65	_	5.5	V	1
Detection temperature*1	+T <sub>D</sub>	_	T <sub>DET</sub> – 2.5	T <sub>DET</sub>	T <sub>DET</sub> + 2.5	°C	1
Hysteresis temperature*2	T <sub>HYS</sub>	_	_	5, 10, 15, 20	-	°C	1
Output voltage	V <sub>DETL</sub>	I <sub>DETL</sub> = 0.5 mA	_	_	0.5	V	3
Leakage current	I <sub>LEAK</sub>	V <sub>DET</sub> = 5.5 V	_	_	0.1	μΑ	4
Current consumption during operation	I <sub>DD</sub>	-	_	0.18	0.5	μΑ	1

<sup>\*1.</sup> T<sub>DET</sub>: Set value of detection temperature

## [Fahrenheit ⇔ Celsius conversion equation]

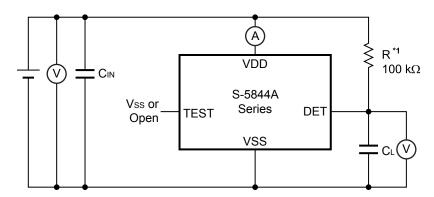
$$^{\circ}$$
C = ( $^{\circ}$ F  $-$  32)  $\times$  5 / 9

 $^{\circ}F = 32 + ^{\circ}C \times 9 / 5$ 

**<sup>\*2.</sup>** The hysteresis temperature is selectable in 5°C, 10°C, 15°C, or 20°C. However, if the detection temperature is +50°C, select the hysteresis temperature in 5°C or 10°C.

<sup>\*2.</sup> The hysteresis temperature is selectable in 5°C, 10°C, 15°C, or 20°C. However, if the detection temperature is +50°C, select the hysteresis temperature in 5°C or 10°C.

### **■** Test Circuits



**\*1.** Resistor (R) is unnecessary for the CMOS output product.

Figure 6 Test Circuit 1

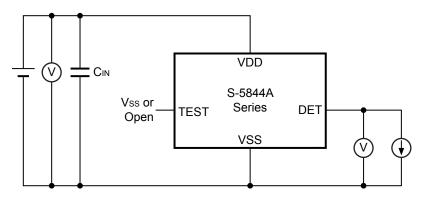


Figure 7 Test Circuit 2

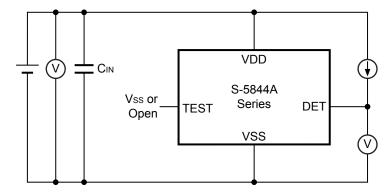


Figure 8 Test Circuit 3

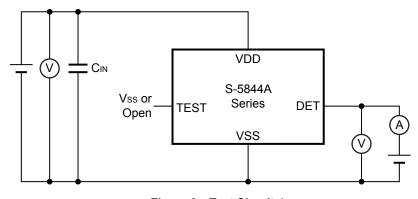


Figure 9 Test Circuit 4

#### Operation

The S-5844A Series is a temperature switch IC (thermostat IC) which detects temperature and sends a signal to an external device.

The users can select various combinations of the parameters such as the detection temperature, the output form and logic, and hysteresis temperature.

Following is about the operation when the DET pin output logic is active "H".

After applying the power supply, the S-5844A Series starts to detect the temperature. If the temperature is lower than the detection temperature  $(+T_D)$ , the DET pin output keeps "L". After that, the temperature rises and exceeds the detection temperature, and the DET pin goes in "H".

After the detection, the temperature drops and reaches the release temperature ( $+T_D - T_{HYS}$ ), the DET pin output returns to "L".

Figure 10 is the timing chart.

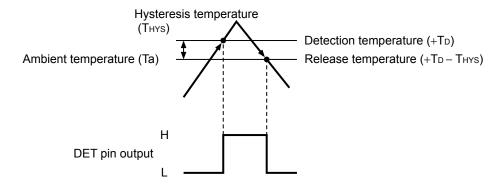
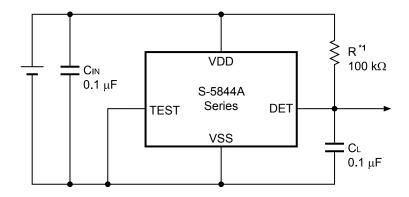


Figure 10 Operation when the DET Pin Output Logic is Active "H"

#### ■ Standard Circuit



\*1. Resistor (R) is unnecessary for the CMOS output product.

Figure 11

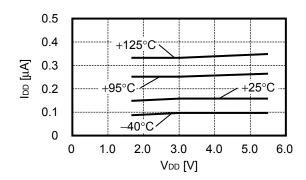
Caution The above connection diagram will not guarantee successful operation. Perform thorough evaluation using actual application to set the constant.

#### ■ Precautions

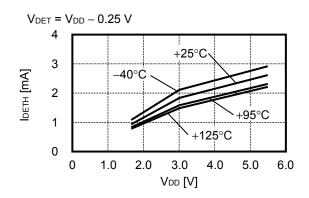
- If power impedance is high, the S-5844A Series may malfunction due to voltage drop caused by feed-through current. Set wire patterns carefully for lower power impedance.
- It is recommended to set a capacitor (C<sub>IN</sub>) of 0.1 μF or more between the VDD pin and VSS pin for stabilization.
- The S-5844A Series may malfunction if the power supply voltage changes suddenly.
- The S-5844A Series is more easily affected by disturbance or noise if the TEST pin is left open.
- It is recommended to set a capacitor ( $C_L$ ) of about 0.1  $\mu F$  for the DET pin to prevent malfunction caused by the noise when the power supply is applied.
- The S-5844A Series may malfunction if the power supply voltage is lower than the minimum operation voltage.
- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
- SII Semiconductor Corporation claims no responsibility for any disputes arising out of or in connection with any infringement by products, including this IC, of patents owned by a third party.

## ■ Characteristics (Typical Data)

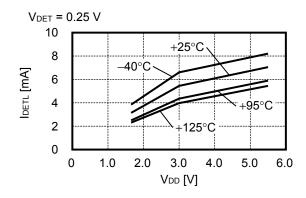
### 1. Current consumption vs. Power supply voltage characteristics



#### 2. DET pin current "H" vs. Power supply voltage characteristics (CMOS output product only)

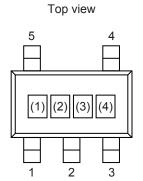


### 3. DET pin current "L" vs. Power supply voltage characteristics



# ■ Marking Specifications

### 1. SOT-23-5



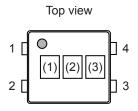
(1) to (3): Product code (refer to **Product name vs. Product code)**(4): Lot number

#### Product name vs. Product code

Due do et Name	Pre	oduct Co	de
Product Name	(1)	(2)	(3)
S-5844A50DB-M5T1U3	2	М	4
S-5844A55CB-M5T1U3	2	М	F
S-5844A55CC-M5T1U3	2	0	F
S-5844A55CD-M5T1U3	2	Q	F
S-5844A55DB-M5T1U3	2	М	Χ
S-5844A60CB-M5T1U3	2	М	G
S-5844A60CC-M5T1U3	2	0	G
S-5844A60CD-M5T1U3	2	Q	G
S-5844A60DB-M5T1U3	2	М	Υ
S-5844A65CB-M5T1U3	2	М	Н
S-5844A65CC-M5T1U3	2	0	Н
S-5844A65CD-M5T1U3	2	Q	Н
S-5844A65DA-M5T1U3	2	K	U
S-5844A65DB-M5T1U3	2	М	Z
S-5844A70CB-M5T1U3	2	М	- 1
S-5844A70CC-M5T1U3	2	0	I
S-5844A70CD-M5T1U3	2	Q	I
S-5844A70DB-M5T1U3	2	М	3
S-5844A75CB-M5T1U3	2	М	Α

5	Pr	oduct Co	de
Product Name	(1)	(2)	(3)
S-5844A75CC-M5T1U3	2	0	Α
S-5844A75CD-M5T1U3	2	Q	Α
S-5844A75DB-M5T1U3	2	М	R
S-5844A80CB-M5T1U3	2	М	В
S-5844A80CC-M5T1U3	2	0	В
S-5844A80CD-M5T1U3	2	Q	В
S-5844A80DB-M5T1U3	2	М	S
S-5844A85CB-M5T1U3	2	М	С
S-5844A85CC-M5T1U3	2	0	С
S-5844A85CD-M5T1U3	2	Q	С
S-5844A85DB-M5T1U3	2	М	Т
S-5844A90CB-M5T1U3	2	М	D
S-5844A90CC-M5T1U3	2	0	D
S-5844A90CD-M5T1U3	2	Q	D
S-5844A90DB-M5T1U3	2	М	U
S-5844A95CB-M5T1U3	2	М	Е
S-5844A95CC-M5T1U3	2	0	Е
S-5844A95CD-M5T1U3	2	Q	Е
S-5844A95DB-M5T1U3	2	М	V

#### 2. SNT-4A



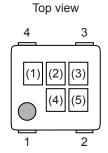
(1) to (3): Product code (refer to **Product name vs. Product code**)

#### Product name vs. Product code

Deed of News	Product Code		
Product Name	(1)	(2)	(3)
S-5844A50DB-I4T1U3	2	М	4
S-5844A55CB-I4T1U3	2	М	F
S-5844A55CC-I4T1U3	2	0	F
S-5844A55CD-I4T1U3	2	Q	F
S-5844A55DB-I4T1U3	2	М	Χ
S-5844A60CB-I4T1U3	2	М	G
S-5844A60CC-I4T1U3	2	0	G
S-5844A60CD-I4T1U3	2	Q	G
S-5844A60DB-I4T1U3	2	М	Υ
S-5844A65CB-I4T1U3	2	М	Н
S-5844A65CC-I4T1U3	2	0	Н
S-5844A65CD-I4T1U3	2	Q	Н
S-5844A65DB-I4T1U3	2	М	Z
S-5844A70CB-I4T1U3	2	М	I
S-5844A70CC-I4T1U3	2	0	- 1
S-5844A70CD-I4T1U3	2	Q	I
S-5844A70DB-I4T1U3	2	М	3
S-5844A75CB-I4T1U3	2	М	Α
S-5844A75CC-I4T1U3	2	0	Α

Product Name	Product Code		
Product Name	(1)	(2)	(3)
S-5844A75CD-I4T1U3	2	Q	Α
S-5844A75DB-I4T1U3	2	М	R
S-5844A80CB-I4T1U3	2	М	В
S-5844A80CC-I4T1U3	2	0	В
S-5844A80CD-I4T1U3	2	Q	В
S-5844A80DB-I4T1U3	2	М	S
S-5844A85CB-I4T1U3	2	М	С
S-5844A85CC-I4T1U3	2	0	С
S-5844A85CD-I4T1U3	2	Q	C
S-5844A85DB-I4T1U3	2	М	Т
S-5844A90CB-I4T1U3	2	М	D
S-5844A90CC-I4T1U3	2	0	D
S-5844A90CD-I4T1U3	2	Q	D
S-5844A90DB-I4T1U3	2	М	U
S-5844A95CB-I4T1U3	2	М	Е
S-5844A95CC-I4T1U3	2	0	Е
S-5844A95CD-I4T1U3	2	Q	Е
S-5844A95DB-I4T1U3	2	М	V

## 3. HSNT-4 (1010)



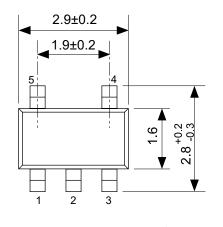
(1) to (3): (4), (5): Product code (refer to  ${f Product\ name\ vs.\ Product\ code})$ 

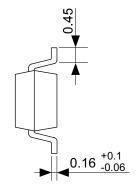
Lot number

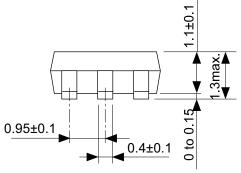
#### Product name vs. Product code

Deadwat Name	Product Code		
Product Name	(1)	(2)	(3)
S-5844A50DB-A4T2U3	2	М	4
S-5844A55CB-A4T2U3	2	М	F
S-5844A55CC-A4T2U3	2	0	F
S-5844A55CD-A4T2U3	2	Q	F
S-5844A55DB-A4T2U3	2	М	Х
S-5844A60CB-A4T2U3	2	М	G
S-5844A60CC-A4T2U3	2	0	G
S-5844A60CD-A4T2U3	2	Q	G
S-5844A60DB-A4T2U3	2	М	Υ
S-5844A65CB-A4T2U3	2	М	Ι
S-5844A65CC-A4T2U3	2	0	Η
S-5844A65CD-A4T2U3	2	Q	Η
S-5844A65DB-A4T2U3	2	М	Z
S-5844A70CB-A4T2U3	2	М	- 1
S-5844A70CC-A4T2U3	2	0	- 1
S-5844A70CD-A4T2U3	2	Q	I
S-5844A70DB-A4T2U3	2	М	3
S-5844A75CB-A4T2U3	2	М	Α
S-5844A75CC-A4T2U3	2	0	Α

Draduct Name	Product Code		
Product Name	(1)	(2)	(3)
S-5844A75CD-A4T2U3	2	Q	Α
S-5844A75DB-A4T2U3	2	М	R
S-5844A80CB-A4T2U3	2	М	В
S-5844A80CC-A4T2U3	2	0	В
S-5844A80CD-A4T2U3	2	Q	В
S-5844A80DB-A4T2U3	2	М	S
S-5844A85CB-A4T2U3	2	М	С
S-5844A85CC-A4T2U3	2	0	С
S-5844A85CD-A4T2U3	2	Q	С
S-5844A85DB-A4T2U3	2	М	Т
S-5844A90CB-A4T2U3	2	М	D
S-5844A90CC-A4T2U3	2	0	D
S-5844A90CD-A4T2U3	2	Q	D
S-5844A90DB-A4T2U3	2	М	U
S-5844A95CB-A4T2U3	2	М	Е
S-5844A95CC-A4T2U3	2	0	Е
S-5844A95CD-A4T2U3	2	Q	Е
S-5844A95DB-A4T2U3	2	М	V

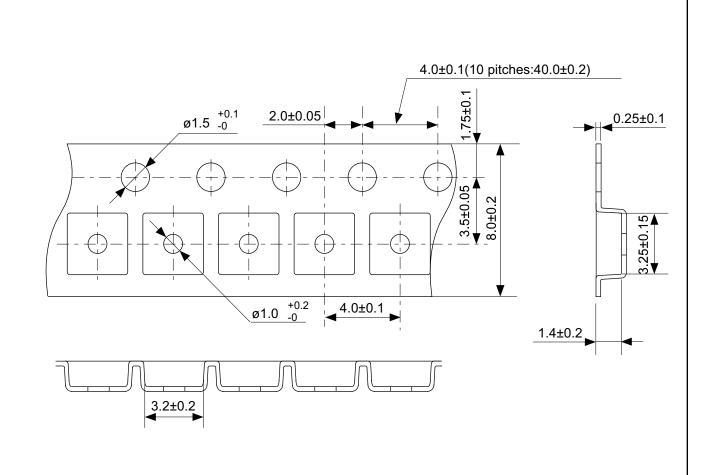


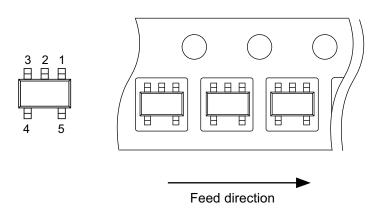




No. MP005-A-P-SD-1.2

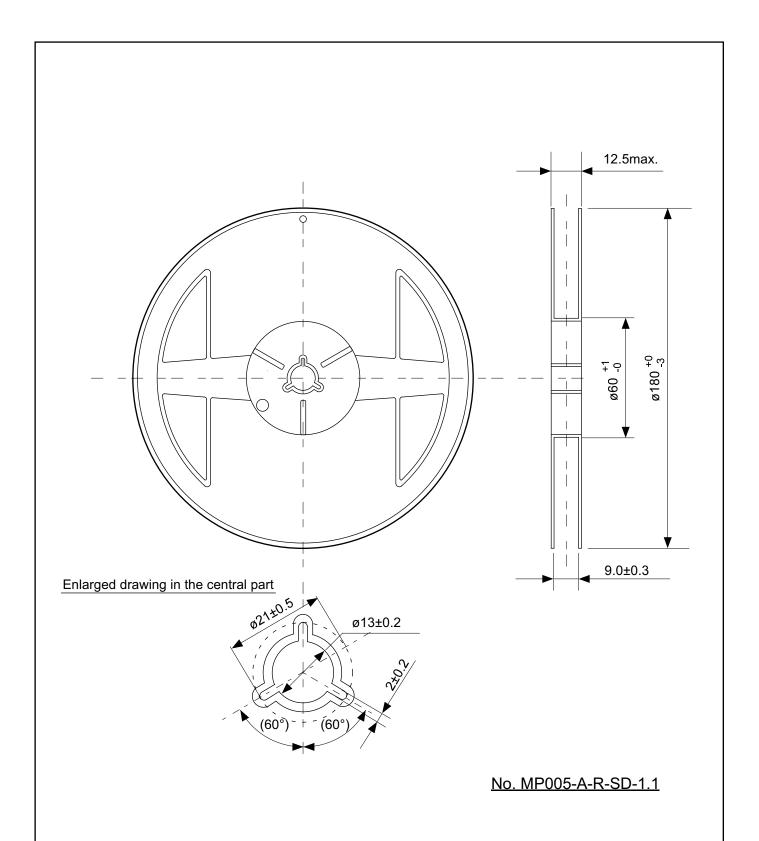
TITLE	SOT235-A-PKG Dimensions
No.	MP005-A-P-SD-1.2
SCALE	
UNIT	mm
SILS	emiconductor Corporation



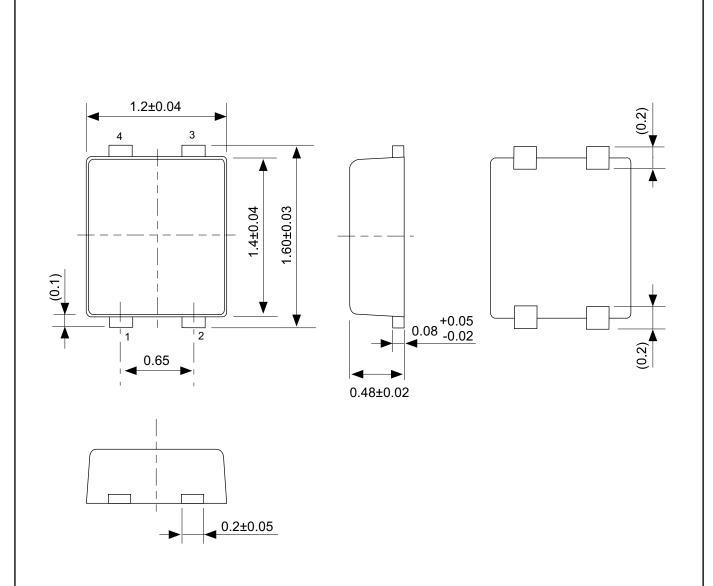


No. MP005-A-C-SD-2.1

TITLE	SOT235-A-Carrier Tape
No.	MP005-A-C-SD-2.1
SCALE	
UNIT	mm
SII S	emiconductor Corporation

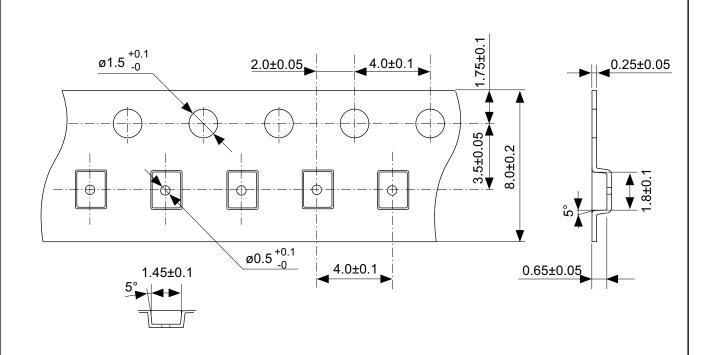


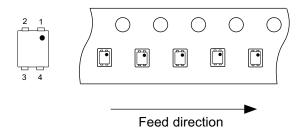
TITLE	SOT235-A-Reel		
No.	MP005-A-R-SD-1.1		
SCALE		QTY.	3,000
UNIT	mm		
SII Semiconductor Corporation			



# No. PF004-A-P-SD-4.0

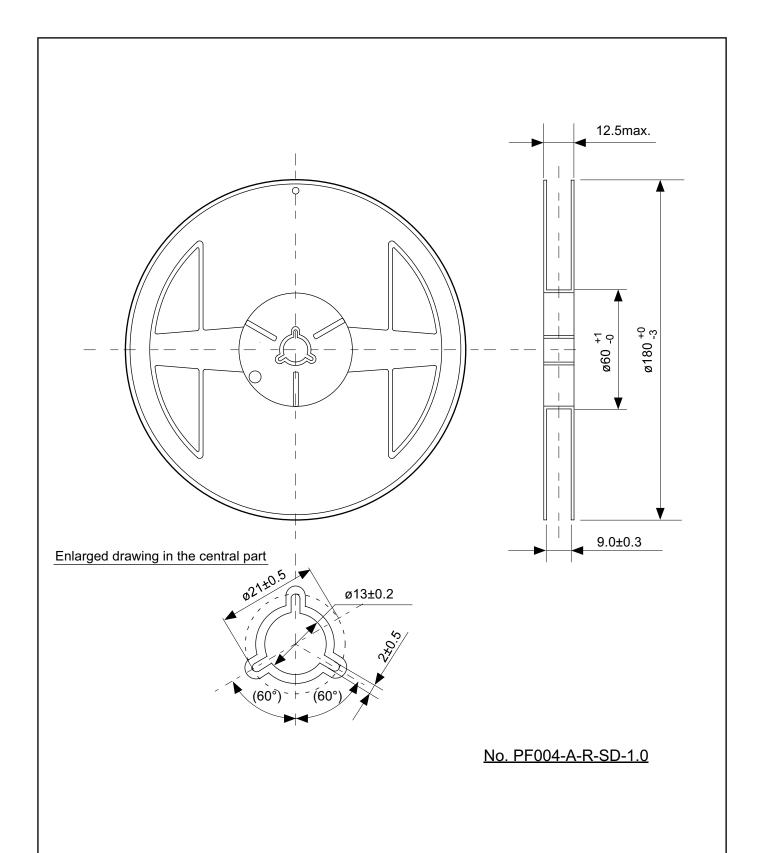
TITLE	SNT-4A-A-PKG Dimensions
No.	PF004-A-P-SD-4.0
SCALE	
UNIT	mm
SII Semiconductor Corporation	
1 311 30	on the state of th



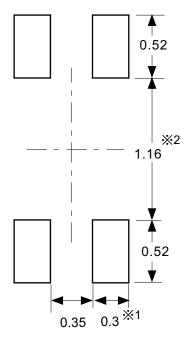


# No. PF004-A-C-SD-1.0

TITLE	SNT-4A-A-Carrier Tape
No.	PF004-A-C-SD-1.0
SCALE	
UNIT	mm
SII Se	emiconductor Corporation



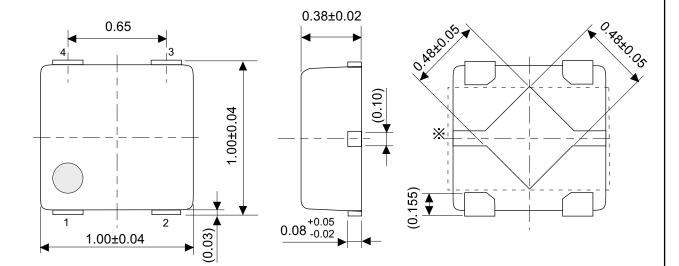
TITLE	SNT-	4A-A-Re	el
No.	PF004-	4-R-SD-1	.0
SCALE		QTY.	5,000
UNIT	mm		
SII Semiconductor Corporation			

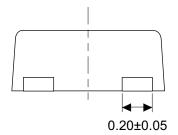


- %1. ランドパターンの幅に注意してください (0.25 mm min. / 0.30 mm typ.)。 %2. パッケージ中央にランドパターンを広げないでください (1.10 mm ~ 1.20 mm)。
- 注意 1. パッケージのモールド樹脂下にシルク印刷やハンダ印刷などしないでください。
  - 2. パッケージ下の配線上のソルダーレジストなどの厚みをランドパターン表面から0.03 mm 以下にしてください。
  - 3. マスク開口サイズと開口位置はランドパターンと合わせてください。
  - 4. 詳細は "SNTパッケージ活用の手引き"を参照してください。
- ※1. Pay attention to the land pattern width (0.25 mm min. / 0.30 mm typ.).
- ※2. Do not widen the land pattern to the center of the package (1.10 mm to 1.20 mm).
- Caution 1. Do not do silkscreen printing and solder printing under the mold resin of the package.
  - 2. The thickness of the solder resist on the wire pattern under the package should be 0.03 mm or less from the land pattern surface.
  - 3. Match the mask aperture size and aperture position with the land pattern.
  - 4. Refer to "SNT Package User's Guide" for details.
- ※1. 请注意焊盘模式的宽度 (0.25 mm min. / 0.30 mm typ.)。
- ※2. 请勿向封装中间扩展焊盘模式 (1.10 mm ~ 1.20 mm)。
- 注意 1. 请勿在树脂型封装的下面印刷丝网、焊锡。
  - 2. 在封装下、布线上的阻焊膜厚度 (从焊盘模式表面起) 请控制在 0.03 mm 以下。
  - 3. 钢网的开口尺寸和开口位置请与焊盘模式对齐。
  - 4. 详细内容请参阅 "SNT 封装的应用指南"。

No. PF004-A-L-SD-4.1

TITLE	SNT-4A-A -Land Recommendation
No.	PF004-A-L-SD-4.1
SCALE	
UNIT	mm
SII Semiconductor Corporation	

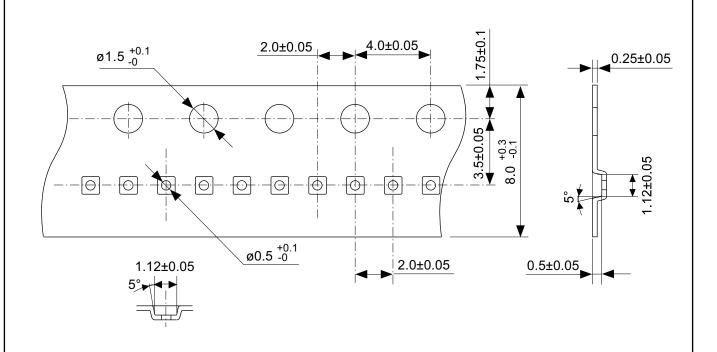


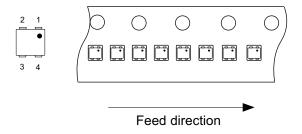


※ The heat sink of back side has different electric potential depending on the product. Confirm specifications of each product. Do not use it as the function of electrode.

# No. PL004-A-P-SD-1.0

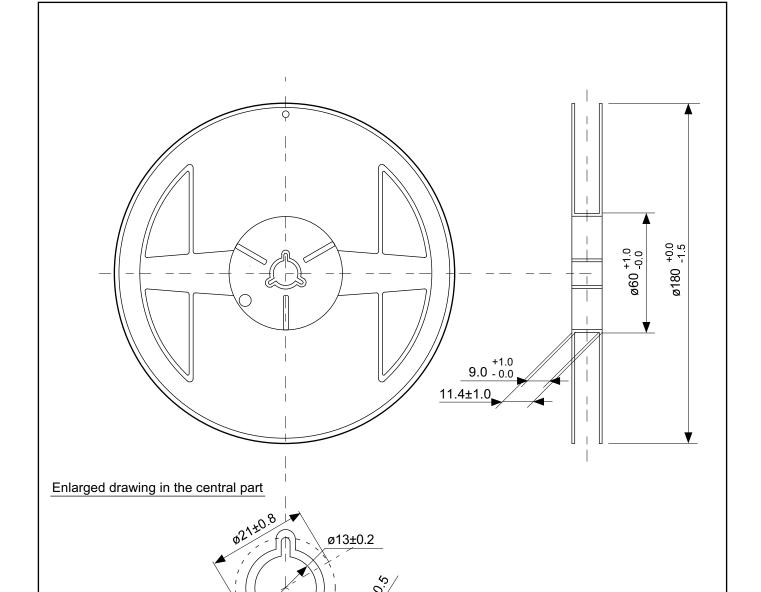
TITLE	HSNT-4-B-PKG Dimensions
No.	PL004-A-P-SD-1.0
SCALE	
UNIT	mm
SII Semiconductor Corporation	





# No. PL004-A-C-SD-1.0

TITLE	HSNT-4-B-Carrier Tape	
No.	PL004-A-C-SD-1.0	
SCALE		
UNIT	mm	
CII C	Laminanduator Carnaration	
SII Semiconductor Corporation		

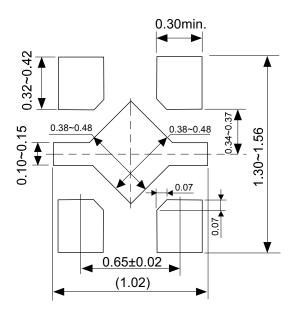


(60°)

# No. PL004-A-R-SD-1.0

TITLE	HSNT-4-B-Reel		
No.	PL004-A-R-SD-1.0		
SCALE		QTY.	10,000
UNIT	mm		
SII Semiconductor Corporation			

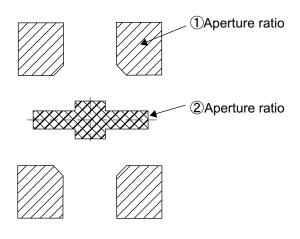
## Land Pattern



Caution It is recommended to solder the heat sink to a board in order to ensure the heat radiation.

放熱性を確保する為に、PKGの裏面放熱板(ヒートシンク)を基板に 注意 半田付けする事を推奨いたします。

### Metal Mask Pattern



- Caution ① Mask aperture ratio of the lead mounting part is 100%.
  - 2 Mask aperture ratio of the heat sink mounting part is 40%.
  - ③ Mask thickness: t0.10mm to 0.12 mm

注意 ①リード実装部のマスク開口率は100%です。

- ②放熱板実装のマスク開口率は40%です。
- ③マスク厚み:t0.10mm~0.12 mm

No. PL004-A-L-SD-2.0

TITLE	HSNT-4-B -Land Recommendation	
No.	PL004-A-L-SD-2.0	
SCALE		
UNIT	mm	
SII Somiconductor Corneration		

SII Semiconductor Corporation

## **Disclaimers (Handling Precautions)**

- 1. All the information described herein (product data, specifications, figures, tables, programs, algorithms and application circuit examples, etc.) is current as of publishing date of this document and is subject to change without notice.
- 2. The circuit examples and the usages described herein are for reference only, and do not guarantee the success of any specific mass-production design.
  - SII Semiconductor Corporation is not responsible for damages caused by the reasons other than the products or infringement of third-party intellectual property rights and any other rights due to the use of the information described herein.
- 3. SII Semiconductor Corporation is not responsible for damages caused by the incorrect information described herein.
- 4. Take care to use the products described herein within their specified ranges. Pay special attention to the absolute maximum ratings, operation voltage range and electrical characteristics, etc.
  - SII Semiconductor Corporation is not responsible for damages caused by failures and/or accidents, etc. that occur due to the use of products outside their specified ranges.
- 5. When using the products described herein, confirm their applications, and the laws and regulations of the region or country where they are used and verify suitability, safety and other factors for the intended use.
- 6. When exporting the products described herein, comply with the Foreign Exchange and Foreign Trade Act and all other export-related laws, and follow the required procedures.
- 7. The products described herein must not be used or provided (exported) for the purposes of the development of weapons of mass destruction or military use. SII Semiconductor Corporation is not responsible for any provision (export) to those whose purpose is to develop, manufacture, use or store nuclear, biological or chemical weapons, missiles, or other military use.
- 8. The products described herein are not designed to be used as part of any device or equipment that may affect the human body, human life, or assets (such as medical equipment, disaster prevention systems, security systems, combustion control systems, infrastructure control systems, vehicle equipment, traffic systems, in-vehicle equipment, aviation equipment, aerospace equipment, and nuclear-related equipment), excluding when specified for in-vehicle use or other uses. Do not use those products without the prior written permission of SII Semiconductor Corporation. Especially, the products described herein cannot be used for life support devices, devices implanted in the human body and devices that directly affect human life, etc.
  - Prior consultation with our sales office is required when considering the above uses.
  - SII Semiconductor Corporation is not responsible for damages caused by unauthorized or unspecified use of our products.
- 9. Semiconductor products may fail or malfunction with some probability.
  - The user of these products should therefore take responsibility to give thorough consideration to safety design including redundancy, fire spread prevention measures, and malfunction prevention to prevent accidents causing injury or death, fires and social damage, etc. that may ensue from the products' failure or malfunction.
  - The entire system must be sufficiently evaluated and applied on customer's own responsibility.
- 10. The products described herein are not designed to be radiation-proof. The necessary radiation measures should be taken in the product design by the customer depending on the intended use.
- 11. The products described herein do not affect human health under normal use. However, they contain chemical substances and heavy metals and should therefore not be put in the mouth. The fracture surfaces of wafers and chips may be sharp. Take care when handling these with the bare hands to prevent injuries, etc.
- 12. When disposing of the products described herein, comply with the laws and ordinances of the country or region where they are used.
- 13. The information described herein contains copyright information and know-how of SII Semiconductor Corporation. The information described herein does not convey any license under any intellectual property rights or any other rights belonging to SII Semiconductor Corporation or a third party. Reproduction or copying of the information described herein for the purpose of disclosing it to a third-party without the express permission of SII Semiconductor Corporation is strictly prohibited.
- 14. For more details on the information described herein, contact our sales office.

1.0-2016.01



# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

#### Seiko Instruments:

S-5844A95CC-I4T1U3 S-5844A85CD-A4T2U3 S-5844A70DB-A4T2U3 S-5844A60CC-A4T2U3 S-5844A55CC-A4T2U3 S-5844A60CB-I4T1U3 S-5844A65DB-A4T2U3 S-5844A80CC-M5T1U3 S-5844A55CB-M5T1U3 S-5844A90CC-M5T1U3 S-5844A70CD-A4T2U3 S-5844A65CB-I4T1U3 S-5844A85CC-A4T2U3 S-5844A75DB-M5T1U3 S-5844A90CD-M5T1U3 S-5844A70CB-A4T2U3 S-5844A80CD-M5T1U3 S-5844A60CB-A4T2U3 S-5844A65DB-M5T1U3 S-5844A60DB-M5T1U3 S-5844A70CD-I4T1U3 S-5844A80CB-M5T1U3 S-5844A75CC-A4T2U3 S-5844A60DB-I4T1U3 S-5844A95CD-I4T1U3 S-5844A80CC-I4T1U3 S-5844A70DB-I4T1U3 S-5844A75CD-I4T1U3 S-5844A90CD-A4T2U3 S-5844A65CB-M5T1U3 S-5844A55CD-A4T2U3 S-5844A60CC-I4T1U3 S-5844A70CC-A4T2U3 S-5844A90CD-I4T1U3 S-5844A80CD-A4T2U3 S-5844A75CC-M5T1U3 S-5844A80CD-I4T1U3 S-5844A70CC-M5T1U3 S-5844A75CD-M5T1U3 S-5844A65CD-I4T1U3 S-5844A65CC-M5T1U3 S-5844A60CC-M5T1U3 S-5844A55CD-I4T1U3 S-5844A95DB-M5T1U3 S-5844A65CC-A4T2U3 S-5844A70CB-I4T1U3 S-5844A75CC-I4T1U3 S-5844A80DB-M5T1U3 S-5844A60CD-A4T2U3 S-5844A55CD-M5T1U3 S-5844A70CB-M5T1U3 S-5844A55CB-I4T1U3 S-5844A70CD-M5T1U3 S-5844A85CB-M5T1U3 S-5844A85CC-M5T1U3 S-5844A95CC-A4T2U3 S-5844A65CB-A4T2U3 S-5844A60DB-A4T2U3 S-5844A55DB-M5T1U3 S-5844A90DB-M5T1U3 S-5844A55CC-I4T1U3 S-5844A60CB-M5T1U3 S-5844A80CC-A4T2U3 S-5844A55CB-A4T2U3 S-5844A55DB-I4T1U3 S-5844A85DB-M5T1U3 S-5844A65CC-I4T1U3 S-5844A90CC-I4T1U3 S-5844A90CB-M5T1U3 S-5844A75CD-A4T2U3 S-5844A55DB-A4T2U3 S-5844A65CD-M5T1U3 S-5844A55CC-M5T1U3 S-5844A85CC-I4T1U3 S-5844A95CD-M5T1U3 S-5844A60CD-I4T1U3 S-5844A85CD-I4T1U3 S-5844A70DB-M5T1U3 S-5844A95CB-M5T1U3 S-5844A60CD-M5T1U3 S-5844A90CC-A4T2U3 S-5844A85CD-M5T1U3 S-5844A65CD-A4T2U3 S-5844A70CC-I4T1U3 S-5844A95CC-M5T1U3 S-5844A75CB-M5T1U3 S-5844A95CD-A4T2U3 S-5844A65DB-I4T1U3 S-5844A85CB-A4T2U3 S-5844A95CB-A4T2U3 S-5844A95DB-I4T1U3 S-5844A75CB-I4T1U3 S-5844A75CB-A4T2U3 S-5844A85CB-I4T1U3 S-5844A80CB-A4T2U3 S-5844A80DB-I4T1U3 S-5844A85DB-I4T1U3 S-5844A90DB-A4T2U3 S-5844A90DB-I4T1U3 S-5844A95CB-I4T1U3